

RJF0614DSP

60V, 1.5A N Channel Thermal FET Power Switching

Datasheet

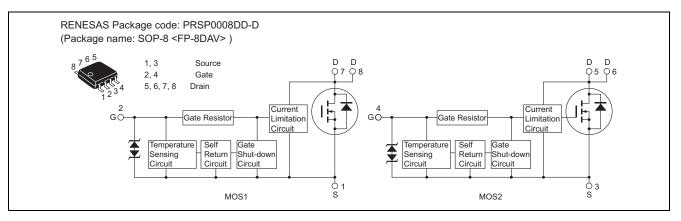
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (5 to 6 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Temperature hysteresis type.
- High density mounting
- Power supply voltage applies 12 V and 24 V.

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V _{GSS}	-2.5	V
Drain current	I _D ^{Note4}	1.5	A
Body-drain diode reverse drain current	I _{DR}	1.5	A
Avalanche current	I _{AP} ^{Note 3}	0.9	A
Avalanche energy	E _{AR} ^{Note 3}	69.4	mJ
Channel dissipation	Pch Note 1	2	W
Channel dissipation	Pch Note 2	3	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. 1 Drive operation: When using the glass epoxy board (FR4 40 \times 40 \times 1.6 mm), PW \leq 10 s

2. 2 Drive operation: When using the glass epoxy board (FR4 40 \times 40 \times 1.6 mm), PW \leq 10 s

3. Tch = 25°C, Rg \geq 50 $\Omega,$ L = 100 mH

4. It provides by the current limitation lower bound value.



Typical Operation Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	—	—	V	
	VIL	_	—	1.2	V	
Input current	I _{IH1}	_	—	100	μA	$Vi = 5 V, V_{DS} = 0$
(Gate non shut down)	I _{IH2}	_	—	50	μA	Vi = 3.5 V, V _{DS} = 0
	IIL	_	—	1	μA	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	0.8	—	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I _{IH(sd)2}		0.35		mA	Vi = 3.5 V, V _{DS} = 0
Shut down temperature	Tsd		175	_	°C	Channel temperature
Return temperature	Thr		120	_	°C	Channel temperature
Gate operation voltage	Vop	3.5	_	12	V	
Drain current (Current limitation value)	I _{D limit}	1.5	—	—	A	$V_{GS} = 5 \text{ V}, V_{DS} = 10 \text{ V}^{\text{ Note 5}}$

Notes: 5. Pulse test

Electrical Characteristics

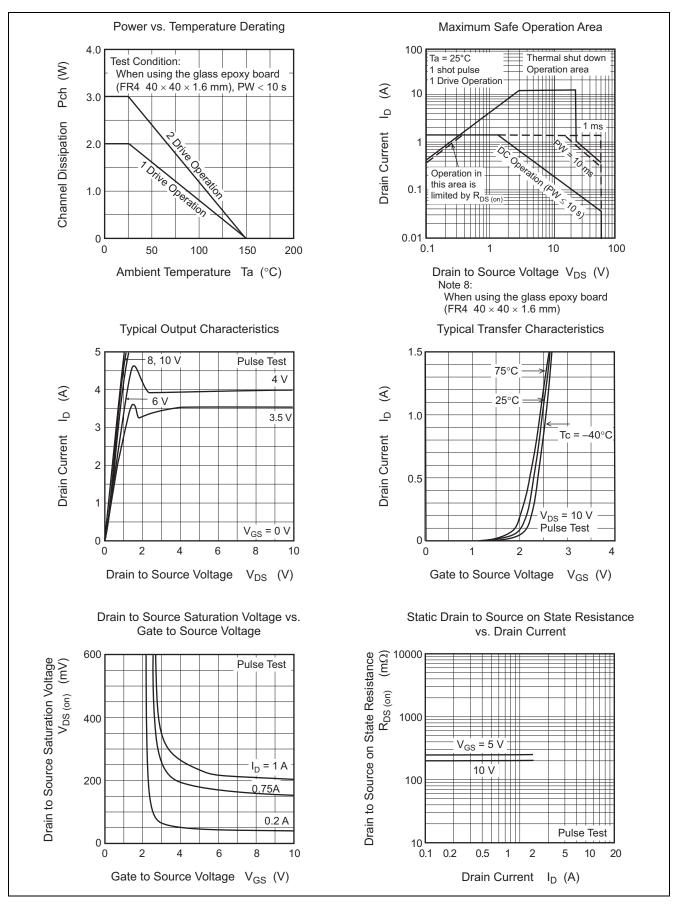
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	5.5	Α	$V_{GS} = 3.5 \text{ V}, V_{DS} = 10 \text{ V}^{Note 6}$
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} =10 V
	I _{D3}	1.5	_		Α	$V_{GS} = 5 \text{ V}, V_{DS} = 10 \text{ V}^{Note 6}$
Drain to source breakdown voltage	V _{(BR)DSS}	60	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR)GSS}	16	_		V	$I_{G} = 800 \ \mu A, \ V_{DS} = 0$
	V _{(BR)GSS}	-2.5	_		V	$I_{G} = -100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS1}		_	100	μA	$V_{GS} = 5 V, V_{DS} = 0$
	I _{GSS2}		_	50	μA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}		_	1	μA	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I _{GSS4}	_	_	-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS(OP)1}	_	0.8		mA	$V_{GS} = 8 V, V_{DS} = 0$
	I _{GS(OP)2}	_	0.35		mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 60 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R _{DS(on)}	_	238	297	mΩ	$I_D = 0.75 \text{ A}, V_{GS} = 5 \text{ V}^{\text{Note 6}}$
resistance	R _{DS(on)}	_	201	250	mΩ	$I_D = 0.75 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 6}}$
Output capacitance	Coss	_	130		pF	$V_{DS} = 10 V, V_{GS} = 0, f = 1MHz$
Turn-on delay time	t _{d(on)}	_	1.4	—	μs	$I_D = 0.75 \text{ A}, V_{GS} = 5 \text{ V},$
Rise time	t _r	_	3.1	—	μs	$R_L = 43 \Omega$
Turn-off delay time	t _{d(off)}	_	3.6		μs	
Fall time	t _f	_	1.9		μs	
Body-drain diode forward voltage	V_{DF}		0.8		V	$I_F = 1.5 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery	t _{rr}	_	910	—	ns	$I_F = 1.5 \text{ A}, V_{GS} = 0$
time						di _F /dt = 50 A/µs
Over load shut down	t _{os1}	_	0.94	—	ms	$V_{GS} = 5 V, V_{DD} = 16 V$
operation time Note 7	t _{os2}	—	0.53	—	ms	$V_{GS} = 5 V, V_{DD} = 24 V$

Notes: 6. Pulse test

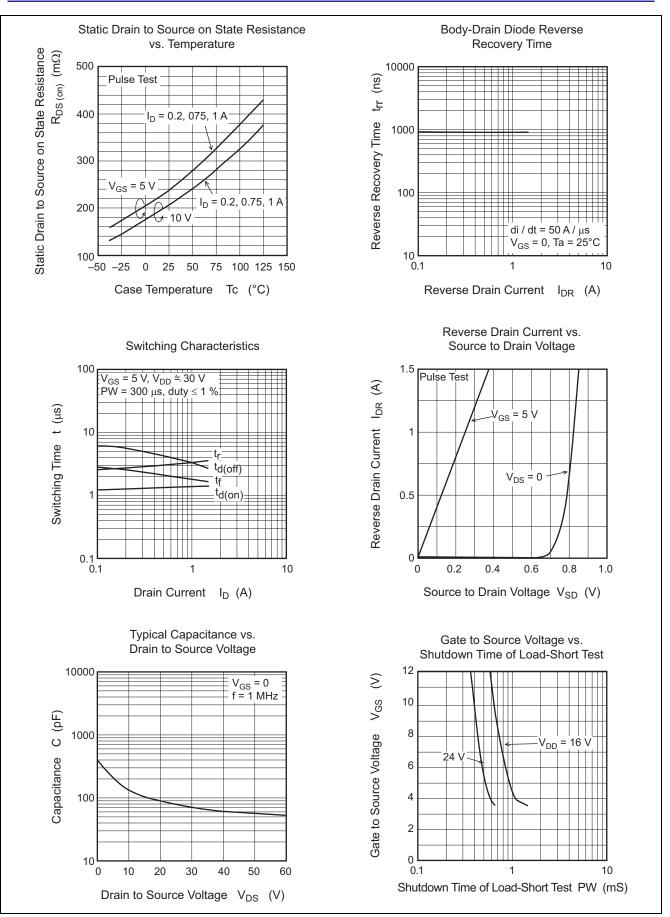
7. Including the junction temperature rise of the over loaded condition.

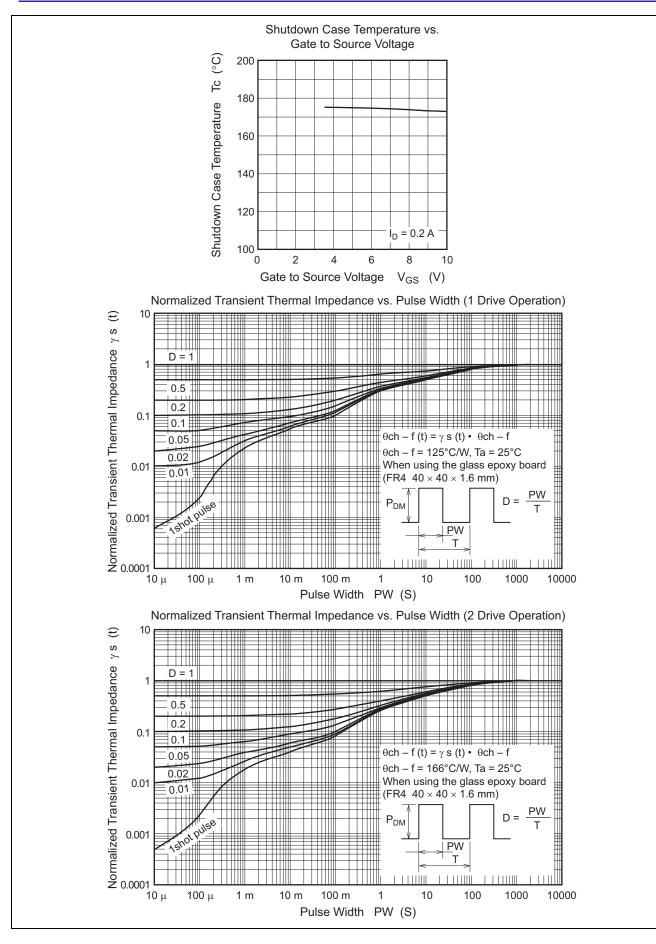


Main Characteristics

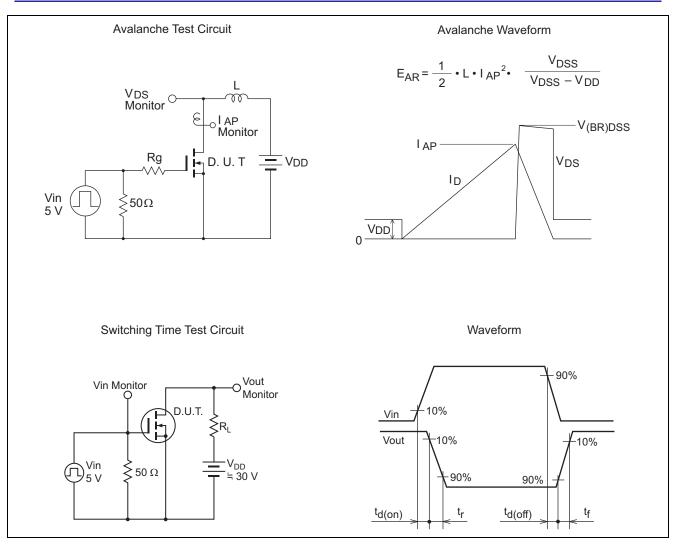






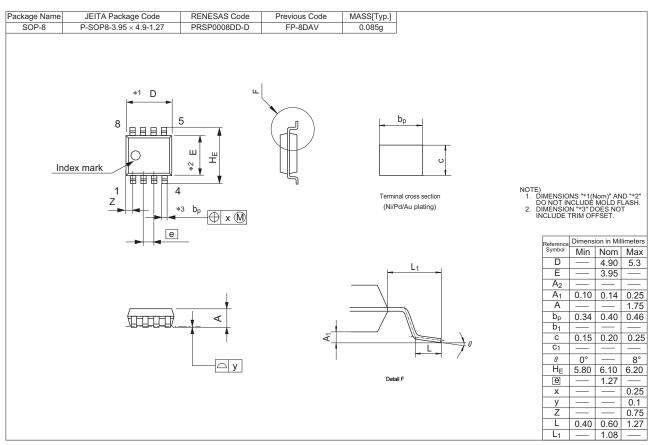








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0614DSP-00#J0	2500 pcs	Taping (Reel)



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